

M1MA151WKT1, M1MA152WKT1

Preferred Device

Common Cathode Silicon Dual Switching Diodes

These Common Cathode Silicon Epitaxial Planar Dual Diodes are designed for use in ultra high speed switching applications. These devices are housed in the SC-59 package which is designed for low power surface mount applications.

- Fast t_{rr} , < 3.0 ns
- Low C_D , < 2.0 pF
- Available in 8 mm Tape and Reel

Use M1MA151/2WKT1 to order the 7 inch/3000 unit reel.

- Pb-Free Packages are Available

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Rating		Symbol	Value	Unit
Reverse Voltage	M1MA151WKT1	V_R	40	Vdc
	M1MA152WKT1		80	
Peak Reverse Voltage	M1MA151WKT1	V_{RM}	40	Vdc
	M1MA152WKT1		80	
Forward Current	Single	I_F	100	mAdc
	Dual		150	
Peak Forward Current	Single	I_{FM}	225	mAdc
	Dual		340	
Peak Forward Surge Current	Single	I_{FSM} (Note 1)	500	mAdc
	Dual		750	

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation	P_D	200	mW
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

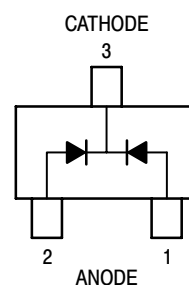
1. $t = 1 \text{ SEC}$



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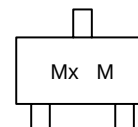
<http://onsemi.com>

**SC-59 PACKAGE SINGLE SILICON
SWITCHING DIODES 40 V/80 V 100 mA
SURFACE MOUNT**



**SC-59
CASE 318D**

MARKING DIAGRAM



x = T for 151
U for 152
M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
M1MA151WKT1	SC-59	3000 / Tape & Reel
M1MA151WKT1G	SC-59 (Pb-Free)	3000 / Tape & Reel
M1MA151WKT1	SC-59	3000 / Tape & Reel
M1MA151WKT1G	SC-59 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

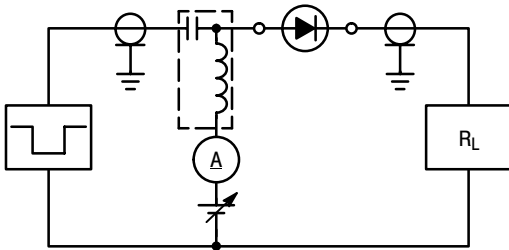
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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

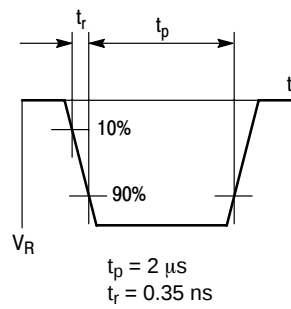
Characteristic		Symbol	Condition	Min	Max	Unit
Reverse Voltage Leakage Current	M1MA151WKT1	I_R	$V_R = 35\text{ V}$	–	0.1	μA_{dc}
	M1MA152WKT1		$V_R = 75\text{ V}$	–	0.1	
Forward Voltage		V_F	$I_F = 100\text{ mA}$	–	1.2	V_{dc}
Reverse Breakdown Voltage	M1MA151WKT1	V_R	$I_R = 100\text{ }\mu\text{A}$	40	–	V_{dc}
	M1MA152WKT1			80	–	
Diode Capacitance		C_D	$V_R = 0, f = 1.0\text{ MHz}$	–	2.0	pF
Reverse Recovery Time (Figure 1)		t_{rr} (Note 2)	$I_F = 10\text{ mA}, V_R = 6.0\text{ V}, R_L = 100\text{ }\Omega, I_{rr} = 0.1\text{ }I_R$	–	3.0	ns

2. t_{rr} Test Circuit

RECOVERY TIME EQUIVALENT TEST CIRCUIT



INPUT PULSE



OUTPUT PULSE

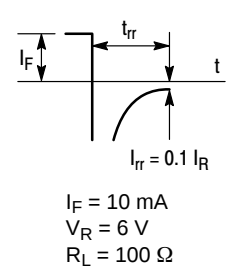
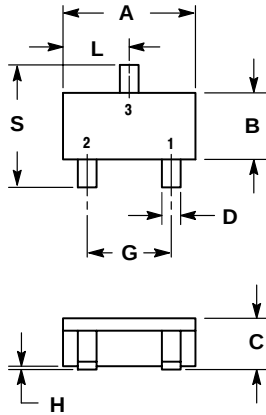


Figure 1. Reverse Recovery Time Equivalent Test Circuit

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PACKAGE DIMENSIONS

SC-59
CASE 318D-04
ISSUE F

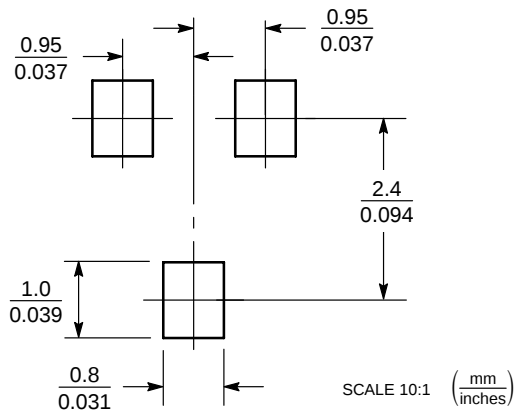


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.70	3.10	0.1063	0.1220
B	1.30	1.70	0.0512	0.0669
C	1.00	1.30	0.0394	0.0511
D	0.35	0.50	0.0138	0.0196
G	1.70	2.10	0.0670	0.0826
H	0.013	0.100	0.0005	0.0040
J	0.09	0.18	0.0034	0.0070
K	0.20	0.60	0.0079	0.0236
L	1.25	1.65	0.0493	0.0649
S	2.50	3.00	0.0985	0.1181

STYLE 3:
PIN 1. ANODE
2. ANODE
3. CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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